NSN 5961-01-124-2158

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-124-2158
Inclosure Material:
Glass
Overall Length:
0.300 inches
Terminal Length:
1.000 inches
Overall Diameter:
Between 0.092 inches and 0.104 inches
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
D0-7
Mounting Method:
Terminal
Terminal Circle Diameter:
0.020 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
6.8 regulator voltage
Current Rating Per Characteristic:
10.00 microamperes forward current, average peak
Power Rating Per Characteristic:
250.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A110a0